



### 60V N-CHANNEL ENHANCEMENT MODE MOSFET PowerDI5060-8

### **Product Summary**

BV <sub>DSS</sub>	R <sub>DS(ON)</sub> Max	I <sub>D</sub> Max T <sub>C</sub> = +25°C
60V	$2.7m\Omega$ @ V <sub>GS</sub> = 10V	163A

### **Description and Applications**

This MOSFET is designed to minimize the on-state resistance (RDS(ON)) yet maintain superior switching performance, making it ideal for high-efficiency power-management applications.

- Switching
- Synchronous rectifications
- DC-DC converters

#### PowerDI5060-8/SWP (Type UX)



**Bottom View** 

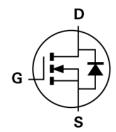
Top View

### **Features**

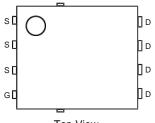
- 100% Unclamped Inductive Switching (UIS) Test in Production Ensures More Reliable and Robust End Application
- Thermally Efficient Package Cooler Running Applications
- High Conversion Efficiency
- Low Rds(ON) Minimizes On-State Losses
- <1.1mm Package Profile Ideal for Thin Applications</li>
- Lead-Free Finish; RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- For automotive applications requiring specific change control (i.e. parts qualified to AEC-Q100/101/104/200, PPAP capable, and manufactured in IATF 16949 certified facilities), please contact us or your local Diodes representative. https://www.diodes.com/guality/product-definitions/

#### **Mechanical Data**

- Package: PowerDI<sup>®</sup>5060-8
- Package Material: Molded Plastic, "Green" Molding Compound.
   UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Weight: 0.097 grams (Approximate)







Top View Pin Configuration

# Ordering Information (Note 4)

Part Number	Paakaga	Packing		
Part Number	Package	Qty.	Carrier	
DMT62M7SPSW-13	PowerDI5060-8/SWP (Type UX)	2,500	Tape & Reel	

Notes:

- 1. EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant. All applicable RoHS exemptions applied.
- 2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
- 4. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/.

## **Marking Information**



☐ ☐ H = Manufacturer's Marking

T62M7SSW = Product Type Marking Code

YYWW = Date Code Marking

YY = Last Two Digits of Year (ex: 23 = 2023)

WW = Week Code (01 to 53)



# **Maximum Ratings** (@ $T_A = +25$ °C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit	
Drain-Source Voltage	VDSS	60	V	
Gate-Source Voltage	V <sub>GSS</sub>	±20	V	
Ocationary Davis Oceans IV 401/ (Note 0)	Tc = +25°C		163	А
Continuous Drain Current, V <sub>GS</sub> = 10V (Note 6)	T <sub>C</sub> = +70°C	ΙD	130	
Pulsed Drain Current (10µs Pulse, Duty Cycle = 1%)	I <sub>DM</sub>	650	Α	
Maximum Continuous Body Diode Forward Current (Note 6)	Is	163	Α	
Pulsed Body Diode Forward Current (10µs Pulse, Duty Cycle = 1%)	lsм	650	Α	
Avalanche Current, L = 0.2mH	I <sub>AS</sub>	45	Α	
Avalanche Energy, L = 0.2mH	Eas	202	mJ	

### **Thermal Characteristics**

Characteristic	Symbol	Value	Unit	
Total Power Dissipation (Note 5)	$T_A = +25^{\circ}C$	PD	2.5	W
Thermal Resistance, Junction to Ambient (Note 5)  Steady State		Reja	50	°C/W
Total Power Dissipation (Note 6)	$T_C = +25^{\circ}C$	$P_{D}$	125	W
Thermal Resistance, Junction to Case (Note 6)	Rejc	1	°C/W	
Operating and Storage Temperature Range	TJ, TSTG	-55 to +150	°C	

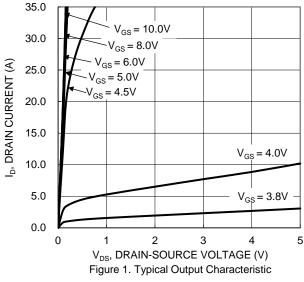
# **Electrical Characteristics** (@T<sub>A</sub> = +25°C, unless otherwise specified.)

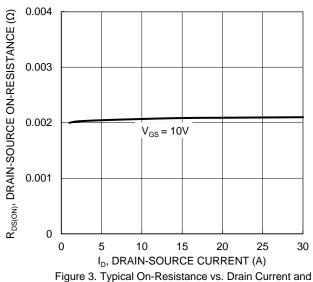
Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition	
OFF CHARACTERISTICS (Note 7)							
Drain-Source Breakdown Voltage	BVDSS	60	_	_	V	$V_{GS} = 0V, I_D = 1mA$	
Zero Gate Voltage Drain Current	IDSS	_	_	1	μA	V <sub>DS</sub> = 48V, V <sub>GS</sub> = 0V	
Gate-Source Leakage	I <sub>GSS</sub>	_	_	±100	nA	$V_{GS} = \pm 20V, V_{DS} = 0V$	
ON CHARACTERISTICS (Note 7)							
Gate Threshold Voltage	V <sub>GS(TH)</sub>	2	_	4	V	$V_{DS} = V_{GS}, I_{D} = 250 \mu A$	
Static Drain-Source On-Resistance	RDS(ON)	_	2.1	2.7	mΩ	Vgs = 10V, ID = 30A	
Diode Forward Voltage	$V_{SD}$	_	0.8	1.2	V	$V_{GS} = 0V, I_{S} = 20A$	
DYNAMIC CHARACTERISTICS (Note 8)							
Input Capacitance	Ciss	_	4973	_		V <sub>DS</sub> = 30V, V <sub>GS</sub> = 0V, f = 1MHz	
Output Capacitance	Coss	1	1613	_	pF		
Reverse Transfer Capacitance	Crss	-	86	_			
Gate Resistance	Rg	_	0.81	_	Ω	$V_{DS} = 0V$ , $V_{GS} = 0V$ , $f = 1MHz$	
Total Gate Charge	Qg	_	68.7	_		V <sub>DD</sub> = 30V, I <sub>D</sub> = 30A,	
Gate-Source Charge	Qgs	_	16.3	_	nC		
Gate-Drain Charge	Q <sub>gd</sub>	_	14.1	_		$V_{GS} = 10V$	
Turn-On Delay Time	tD(ON)	_	11.45	_		$V_{DD} = 30V, V_{GS} = 10V,$ $I_{D} = 30A, R_{g} = 3.5\Omega$	
Turn-On Rise Time	t <sub>R</sub>		10.68	_			
Turn-Off Delay Time	t <sub>D(OFF)</sub>		33.01	_	ns		
Turn-Off Fall Time	tr		14.86	_			
Reverse Recovery Time	t <sub>RR</sub>	_	53.34	_	ns	1 000 11/11 1000/	
Reverse Recovery Charge	Qrr	_	90.49	_	nC	IF = 30A, di/dt = 100A/µs	

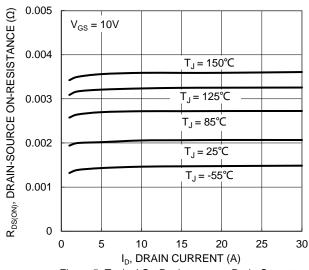
Notes:

- Device mounted on FR-4 substrate PC board, 2oz copper, with thermal bias to bottom layer 1inch square copper plate.
   Thermal resistance from junction to soldering point (on the exposed drain pad).
   Short duration pulse test used to minimize self-heating effect.
   Guaranteed by design. Not subject to product testing.

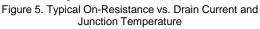








Gate Voltage



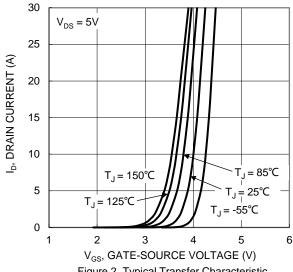
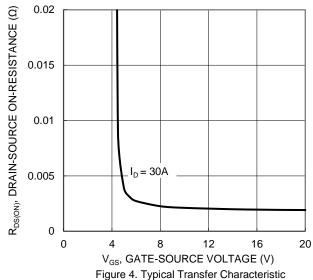


Figure 2. Typical Transfer Characteristic



2.2 R<sub>DS(ON)</sub>, DRAIN-SOURCE ON-RESISTANCE (NORMALIZED) 2 1.8 1.6 1.4  $V_{GS} = 10V, I_{D} = 30A$ 1.2 8.0 0.6 0 -50 -25 25 50 75 100 125 150 T<sub>J</sub>, JUNCTION TEMPERATURE (°C)

Figure 6. On-Resistance Variation with Junction Temperature





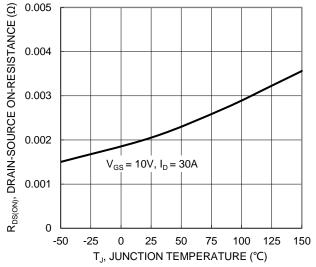
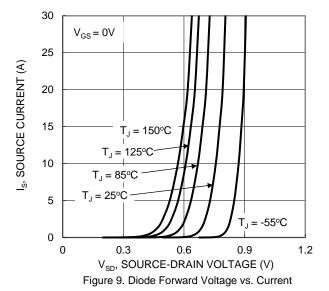
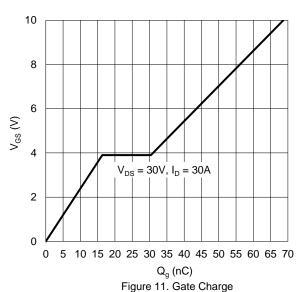


Figure 7. On-Resistance Variation with Junction Temperature





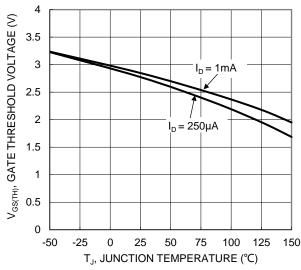
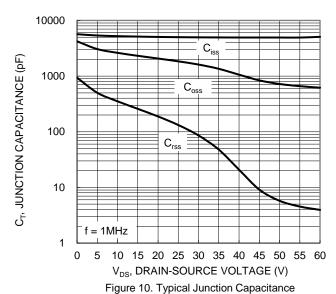


Figure 8. Gate Threshold Variation vs. Junction Temperature



1000 R<sub>DS(ON)</sub> Limited 100 ID, DRAIN CURRENT (A)  $P_W = 10 \mu s$ 10  $P_{W}$  $= 100 \mu s$  $P_W = 10ms$ P<sub>W</sub> = 100ms  $T_{J(Max)} = 150$ °C T<sub>C</sub> = 25°C Single Pulse 0.1 DUT on Infinite Heatsink  $V_{GS} = 10V$ 0.01 0.1 10 100 V<sub>DS</sub>, DRAIN-SOURCE VOLTAGE (V) Figure 12. SOA, Safe Operation Area



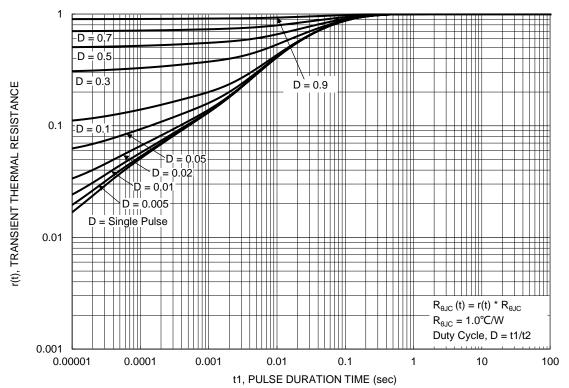


Figure 13. Transient Thermal Resistance



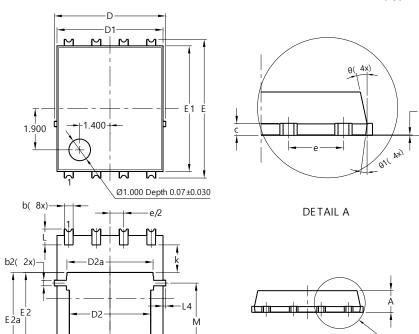
# **Package Outline Dimensions**

Please see http://www.diodes.com/package-outlines.html for the latest version.

### PowerDI5060-8/SWP (Type UX)

Seating Plane

DETAIL A



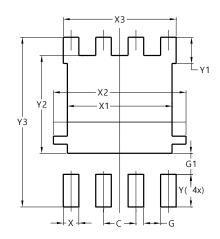
PowerDI5060-8/SWP					
(Type UX)					
Dim	Min	Max	Тур		
Α	0.90	1.10	1.00		
A1	0	0.05			
b	0.30	0.50	0.41		
b2	0.20	0.35	0.25		
b4		).25REF	-		
С	0.230	0.330	0.277		
D	5	.15 BS0	2		
D1	4.70	5.10	4.90		
D2	3.56	3.96	3.76		
D2a	3.78	4.18	3.98		
Е	6	.40 BS0	2		
E1	5.60	6.00	5.80		
E2	3.46	3.86	3.66		
E2a	4.195	4.595	4.395		
е	1.27BSC				
k	1.05				
L	0.635	0.835	0.735		
La	0.635	0.835	0.735		
L1	0.200	0.400	0.300		
L1a	0.050REF				
L4	0.025	0.225	0.125		
M	3.205	4.005	3.605		
θ	10°	12°	11°		
θ1	6°	8°	7°		
All Dimensions in mm					

# **Suggested Pad Layout**

Please see http://www.diodes.com/package-outlines.html for the latest version.

-b4( 8x)

#### PowerDI5060-8/SWP (Type UX)



Dimensions	Value (in mm)		
C	1.270		
G	0.660		
G1	0.820		
X	0.610		
X1	4.100		
X2	5.190		
Х3	4.420		
Υ	1.270		
Y1	1.020		
Y2	3.810		
Y3	6.610		



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